

DMTH4004LPSQ-13 Datasheet



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DiGi Electronics Part Number DMTH4004LPSQ-13-DG

Manufacturer Diodes Incorporated

Manufacturer Product Number DMTH4004LPSQ-13

Description MOSFET N-CH 40V 100A PWRDI5060-8

Detailed Description N-Channel 40 V 100A (Tc) 2.83W (Ta), 125W (Tc) Su

rface Mount PowerDI5060-8



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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
DMTH4004LPSQ-13	Diodes Incorporated
Series:	Product Status:
	Active
FET Type:	Technology:
N-Channel	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	Current - Continuous Drain (Id) @ 25°C:
40 V	100A (Tc)
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ Id, Vgs:
4.5V, 10V	2.5mOhm @ 50A, 10V
Vgs(th) (Max) @ Id:	Gate Charge (Qg) (Max) @ Vgs:
3V @ 250μA	69.6 nC @ 10 V
Vgs (Max):	Input Capacitance (Ciss) (Max) @ Vds:
±20V	5220 pF @ 20 V
FET Feature:	Power Dissipation (Max):
	2.83W (Ta), 125W (Tc)
Operating Temperature:	Grade:
-55°C ~ 175°C (TJ)	Automotive
Qualification:	Mounting Type:
AEC-Q101	Surface Mount
Supplier Device Package:	Package / Case:
PowerDI5060-8	8-PowerTDFN
Base Product Number:	
DMTH4004	

Environmental & Export classification

8541.29.0095

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	





40V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _C = +25°C (Note 9)
40\/	2.5mΩ @ V _G S = 10V	100A
40V	5mΩ @ V _{GS} = 4.5V	100A

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Engine management systems
- · Body control electronics
- DC-DC converters

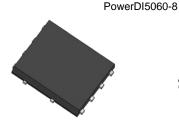
Features

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- Low Rds(ON) Minimizes Power Losses
- Low Q_q Minimizes Switching Losses
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMTH4004LPSQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

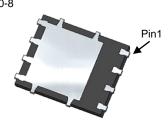
https://www.diodes.com/quality/product-definitions/

Mechanical Data

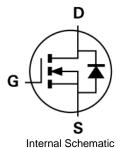
- Package: PowerDI[®]5060-8
- Package Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (§3)
- Weight: 0.097 grams (Approximate)

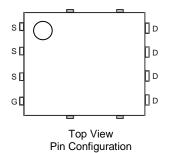


Top View



Bottom View





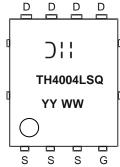
Ordering Information (Note 4)

Part Number	Dackers	Packing		
Part Number	Package	Qty.	Carrier	
DMTH4004LPSQ-13	PowerDI5060-8	2,500	Tape & Reel	

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information



⊃ | | = Manufacturer's Code Marking TH4004LSQ = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 24 = 2024) WW = Week (01 to 53)



Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		VDSS	40	V
Gate-Source Voltage		Vgss	±20	V
Continuous Drain Current (Notes 6 % 0)	Tc = +25°C	,	100	Δ.
Continuous Drain Current (Notes 6 & 9) T _C = +'		ID	100	A
Maximum Continuous Body Diode Forward Current (Note 6)		Is	100	Α
Pulsed Drain Current (380µs Pulse, Duty Cycle = 1%)		I _{DM}	400	Α
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)		lsм	400	Α
Avalanche Current, L = 0.2mH		I _{AS}	53.2	Α
Avalanche Energy, L = 0.2mH		Eas	283	mJ

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	$T_A = +25^{\circ}C$	PD	2.83	W
Thermal Resistance, Junction to Ambient (Note 5)		Reja	53	°C/W
Total Power Dissipation (Note 6)	Tc = +25°C	PD	125	W
Thermal Resistance, Junction to Case (Note 6)	•	Rejc	1.2	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Electrical Characteristics ($@T_A = +25$ °C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	40	_	_	V	$V_{GS} = 0V$, $I_D = 1mA$	
Zero Gate Voltage Drain Current	IDSS	l	_	1	μΑ	$V_{DS} = 32V$, $V_{GS} = 0V$	
Gate-Source Leakage	Igss			±100	nA	$V_{GS} = \pm 20V$, $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	VGS(TH)	1	_	3	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$	
Static Drain-Source On-Resistance	0		2.14	2.5	mΩ	Vgs = 10V, ID = 50A	
Static Dialii-Source Off-Resistance	R _{DS(ON)}	_	3.85	5	11177	$V_{GS} = 4.5V, I_{D} = 50A$	
Diode Forward Voltage	VsD	_	0.85	1.2	V	V _G S = 0V, I _S = 50A	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss		5220	_		V _{DS} = 20V, V _{GS} = 0V, f = 1MHz	
Output Capacitance	Coss		1734	_	pF		
Reverse Transfer Capacitance	Crss	1	79	_		1 - 11011 12	
Gate Resistance	Rg		0.59	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (VGS = 4.5V)	Qg	_	32.4	_	nC		
Total Gate Charge (VGS = 10V)	Qg	_	69.6	_],,,	
Gate-Source Charge	Qgs	_	13	_	nC	$V_{DD} = 20V, I_D = 30A$	
Gate-Drain Charge	Qgd	_	14.7	_			
Turn-On Delay Time	tD(ON)	_	9.0	_		$V_{DD} = 20V, V_{GS} = 10V,$ $I_{D} = 30A, R_{g} = 1.6\Omega$	
Turn-On Rise Time	t _R		10.4	_			
Turn-Off Delay Time	tD(OFF)	_	24.4	_	ns		
Turn-Off Fall Time	t _F		6.0	_			
Body Diode Reverse Recovery Time	trr	_	54.3	_	ns	L 50A (1/4) 400A/	
Body Diode Reverse Recovery Charge	Q _{RR}		89.5	_	nC	I _F = 50A, di/dt = 100A/μs	

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.

- 6. Thermal resistance from junction to soldering point (on the exposed drain pad).7. Short duration pulse test used to minimize self-heating effect.
- Short duration pulse test used to minimize self-neating effect
 Guaranteed by design. Not subject to production testing.
- 9. Limited by package.

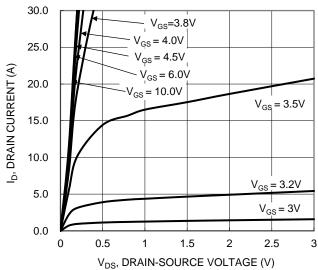
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 $V_{DS} = 5V$



DMTH4004LPSQ



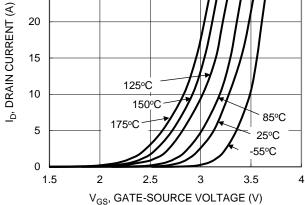
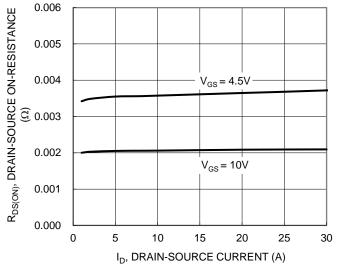


Figure 1. Typical Output Characteristic

Figure 2. Typical Transfer Characteristic



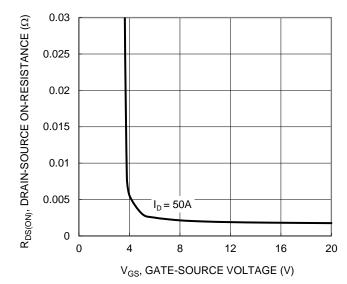
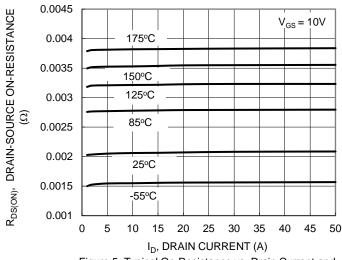


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

Figure 4. Typical Transfer Characteristic



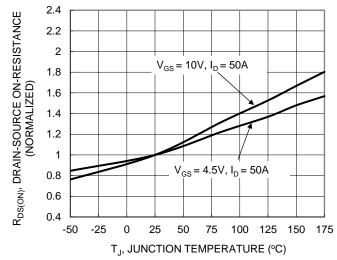


Figure 5. Typical On-Resistance vs. Drain Current and Temperature

Figure 6. On-Resistance Variation with Temperature



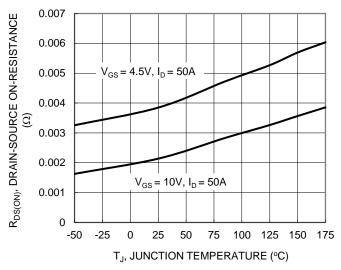


Figure 7. On-Resistance Variation with Temperature

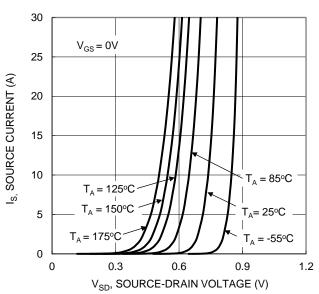
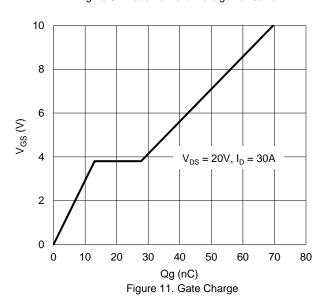
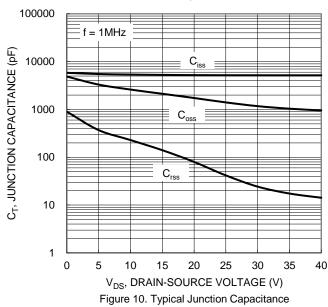


Figure 9. Diode Forward Voltage vs. Current



3 $V_{GS(TH)}$, GATE THRESHOLD VOLTAGE (V) 2.8 2.6 2.4 $I_D = 1 \text{mA}$ 2.2 2 1.8 $I_{D} = 250 \mu A$ 1.6 1.4 1.2 0.8 0.6 0.4 0.2 -50 -25 100 125 150 175 25 50 75 T_{.I}, JUNCTION TEMPERATURE (°C)

Figure 8. Gate Threshold Variation vs. Junction Temperature



1000 R_{DS(ON)} 100 ID, DRAIN CURRENT (A) 10 = 100ms $T_{J(Max)} = 175^{\circ}C$ $T_C = 25^{\circ}C$ Single Pulse DC DUT on Infinite Heatsink $V_{GS} = 10V$ 0.1 0.1 100 10 V_{DS}, DRAIN-SOURCE VOLTAGE (V)

Figure 12. SOA, Safe Operation Area



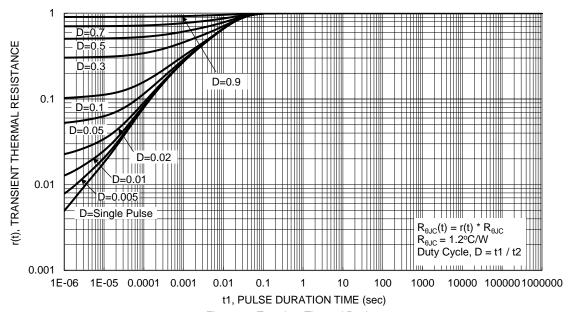


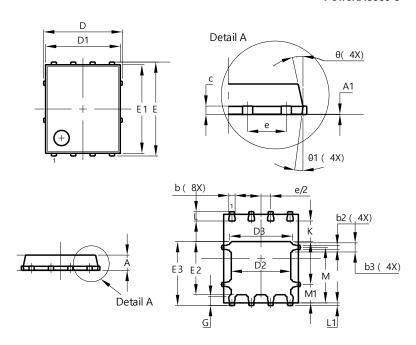
Figure 13. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8

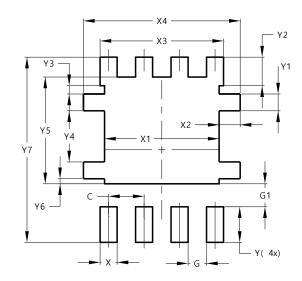


PowerDI5060-8					
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0.00	0.05	-		
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
С	0.230	0.330	0.277		
D	ţ	5.15 BSC			
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90	4.30	4.10		
Е	(6.15 BSC	;		
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	4.39	4.19		
е	1.27 BSC				
G	0.51	0.71	0.61		
K	0.51	-	-		
٦	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
M	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
Θ	10°	12°	11°		
Θ1	6°	8°	7°		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
X	0.610
X1	4.100
X2	0.755
Х3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610



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